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- Qualified for Automotive Applications
- 2.7-V and 5-V Performance
- No Crossover Distortion
- Low Supply Current:

LMV321 . . . 130 μ A Typ LMV358 . . . 210 μ A Typ LMV324 . . . 410 μ A Typ

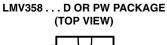
Rail-to-Rail Output Swing

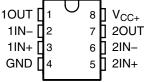
description/ordering information

The LMV321, LMV358, and LMV324 are single, dual, and quad low-voltage (2.7 V to 5.5 V) operational amplifiers with rail-to-rail output swing.

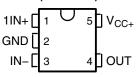
The LMV321, LMV358, and LMV324 are the most cost-effective solution for applications where low-voltage operation, space saving, and low price are required. These amplifiers were designed specifically for low-voltage (2.7 V to 5 V) operation, with performance specifications meeting or exceeding the LM358 and LM324 devices that operate from 5 V to 30 V. Additional features of the LMV3xx devices are a common-mode input voltage range that includes ground, 1-MHz unity-gain bandwidth, and 1-V/μs slew rate.

LMV324 . . . D OR PW PACKAGE (TOP VIEW) 14 1 40UT 10UT [1IN- [13 AIN-1IN+ [] 3 12 4IN+ V_{CC+} **□** 4 11 **∏** GND 2IN+ [] 5 10 ¶ 3IN+ 2IN− ¶ 6 9 3IN-20UT [8**∏** 30UT





LMV321 . . . DBV PACKAGE (TOP VIEW)





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



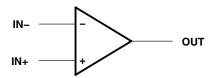
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ORDERING INFORMATION[†]

T _A		PACKA	AGE [†]	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
-40°C to 85°C	Single	SOT23-5 (DBV)	Reel of 3000	LMV321IDBVRQ1	RC1B	
		0010 (D)	Tube of 75	LMV358IDQ1	050104	
-40°C to 85°C	Dual	SOIC (D)	Reel of 2500	LMV358IDRQ1	358IQ1	
		TSSOP (PW)	Reel of 2000	LMV358IPWRQ1	358IQ1	
		0010 (D)	Tube of 50	LMV324IDQ1	1111/004104	
–40°C to 85°C	Quad	SOIC (D)	Reel of 2500	LMV324IDRQ1	LMV324IQ1	
		TSSOP (PW)	Reel of 2000	LMV324IPWRQ1	V324IQ1	
-40°C to 125°C	Single	SOT23-5 (DBV)	Reel of 3000	LMV321QDBVRQ1	RCCB	
		0010 (D)	Tube of 75	LMV358QDQ1	1/05004	
-40°C to 125°C	Dual	SOIC (D)	Reel of 2500	LMV358QDRQ1	V358Q1	
		TSSOP (PW)	Reel of 2000	LMV358QPWRQ1	V358Q1	
-40°C to 125°C		0010 (D)	Tube of 50	LMV324QDQ1	1.1.1.1.0.1.0.1	
	Quad	SOIC (D)	Reel of 2500	LMV324QDRQ1	LMV324Q1	
		TSSOP (PW)	Reel of 2000	LMV324QPWRQ1	MV324Q1	

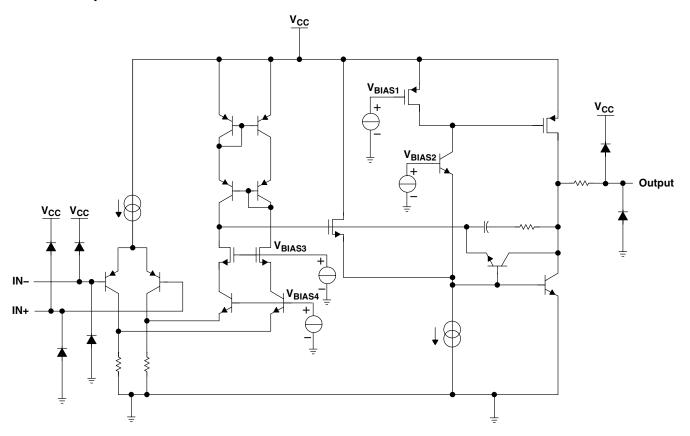
[†] For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at http://www.ti.com.

symbol (each amplifier)



[‡] Package drawings, thermal data, and symbolization are available at http://www.ti.com/packaging.

LMV324 simplified schematic



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC} (see Note 1)	
Differential input voltage, V _{ID} (see Note 2)	
Input voltage, V _I (either input)	
Duration of output short circuit (one amplifier) to ground	d at (or below) T _A = 25°C,
V _{CC} ≤ 5.5 V (see Note 3)	
Package thermal impedance, θ_{JA} (see Notes 4 and 5):	D (8-pin) package 97°C/W
	D (14-pin) package
	DBV (5-pin) package 206°C/W
	PW (8-pin) package 149°C/W
	PW (14-pin) package 113°C/W
Operating virtual junction temperature, T _J	
Storage temperature range, T _{stg}	–65 to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values (except differential voltages and V_{CC} specified for the measurement of I_{OS}) are with respect to the network GND.

- Differential voltages are at IN+ with respect to IN-.
- 3. Short circuits from outputs to $V_{\mbox{\footnotesize CC}}$ can cause excessive heating and eventual destruction.
- 4. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Selecting the maximum of 150°C can affect reliability.
- 5. The package thermal impedance is calculated in accordance with JESD 51-7.



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recommended operating conditions (see Note 6)

			MIN	MAX	UNIT
V_{CC}	Supply voltage (single-supply operation)		2.7	5.5	V
V _{IH}	A 197	V _{CC} = 2.7 V	1.7		.,
	Amplifier turn-on voltage level	V _{CC} = 5 V	3.5		V
V _{IL}	A 100 - 10 - 1	V _{CC} = 2.7 V		0.7	.,
	Amplifier turn-off voltage level	V _{CC} = 5 V		1.5	V
T _A		I suffix	-40	85	20
	Operating free-air temperature	-40	125	°C	

NOTE 6: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics at T_A = 25°C, V_{CC+} = 2.7 V (unless otherwise noted)

	PARAMETER	TEST COND	DITIONS	MIN	TYP	MAX	UNIT
V _{IO}	Input offset voltage				1.7	7	mV
$\alpha_{V_{IO}}$	Average temperature coefficient of input offset voltage				5		μV/°C
I _{IB}	Input bias current				11	250	nA
I _{IO}	Input offset current				5	50	nA
CMRR	Common-mode rejection ratio	V _{CM} = 0 to 1.7 V		50	63		dB
k _{SVR}	Supply-voltage rejection ratio	$V_{CC} = 2.7 \text{ V to 5 V},$	V _O = 1 V	50	60		dB
V _{ICR}	Common-mode input voltage range	CMRR ≥ 50 dB		0 to 1.7	-0.2 to 1.9		V
	0	D 40101 40514	High level	V _{CC} – 100	V _{CC} – 10		
	Output swing	$R_L = 10 \text{ k}\Omega \text{ to } 1.35 \text{ V}$	Low level		60	180	mV
		LMV321			80	170	
I _{CC}	Supply current	LMV358 (both amplifiers		140	340	μΑ	
		LMV324 (all four amplifi	ers)		260	680	
B ₁	Unity-gain bandwidth	C _L = 200 pF			1		MHz
фт	Phase margin				60		deg
G _m	Gain margin				10		dB
V _n	Equivalent input noise voltage	f = 1 kHz			46		nV/√ Hz
In	Equivalent input noise current	f = 1 kHz			0.17		pA/√ Hz

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electrical characteristics at specified free-air temperature range, $V_{CC+} = 5 \text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A †	MIN	TYP	MAX	UNIT	
V Input offeet voltage				25°C		1.7	7	.,	
V_{IO}	Input offset voltage			Full range			9	mV	
$\alpha_{V_{IO}}$	Average temperature coefficient of input offset voltage			25°C		5		μV/°C	
	lancik bisa sumank			25°C		15	250	^	
I _{IB}	Input bias current			Full range			500	nA	
	hand affect account			25°C		5	50	4	
I _{IO}	Input offset current			Full range			150	nA	
CMRR	Common-mode rejection ratio	V _{CM} = 0 to 4 V		25°C	50	65		dB	
k _{SVR}	Supply-voltage rejection ratio	$V_{CC} = 2.7 \text{ V to 5 V, V}_{CM} = 1 \text{ V}$) = 1 V,	25°C	50	60		dB	
V _{ICR}	Common-mode input voltage range	CMMR ≥ 50 dB		25°C	0 to 4	-0.2 to 4.2		٧	
			High	25°C	V _{CC} – 300	V _{CC} – 40		mV	
		D 2101 251	level	Full range	V _{CC} – 400				
		$R_L = 2 k\Omega$ to 2.5 V	Low	25°C		120	300		
	Outrast audia a		level	Full range			400		
	Output swing	D 1010 to 0.5 V	High level	25°C	V _{CC} – 100	V _{CC} – 10			
				Full range	V _{CC} – 200				
		$R_L = 10 \text{ k}\Omega \text{ to } 2.5 \text{ V}$	Low	25°C		65	180		
		leve		Full range			280		
۸	Large-signal differential	D 0k0	5 010		15	100		V/mV	
A_{VD}	voltage gain	$R_L = 2 k\Omega$		Full range	10			V/IIIV	
1	Output short-circuit current	Sourcing, V _O = 0 V		25°C	5	60		m 1	
I _{OS}	Output short-circuit current	Sinking, V _O = 5 V		25 C	10	160		mA	
		LMV321		25°C		130	250		
		LIVIVOZI		Full range			350		
Icc	Supply current	LMV358 (both amplifiers)		25°C		210	440	μΑ	
icc	Supply current	LIVIV 336 (DOLLI ALTIPIIIIE	=15)	Full range			615	μΛ	
		LMV324 (all four ampl	ifiere)	25°C		410	830		
		LMV324 (all four amplifiers)		Full range			1160		
B ₁	Unity-gain bandwidth	C _L = 200 pF		25°C		1		MHz	
φ_{m}	Phase margin			25°C		60		deg	
G _m	Gain margin			25°C		10		dB	
V _n	Equivalent input noise voltage	f = 1 kHz		25°C		39		nV/√ Hz	
In	Equivalent input noise current	f = 1 kHz		25°C		0.21		pA/√ Hz	
SR	Slew rate			25°C		1		V/μs	

[†] Full range is -40°C to 85°C for I-level part, -40°C to 125°C for Q-level part.

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TYPICAL CHARACTERISTICS

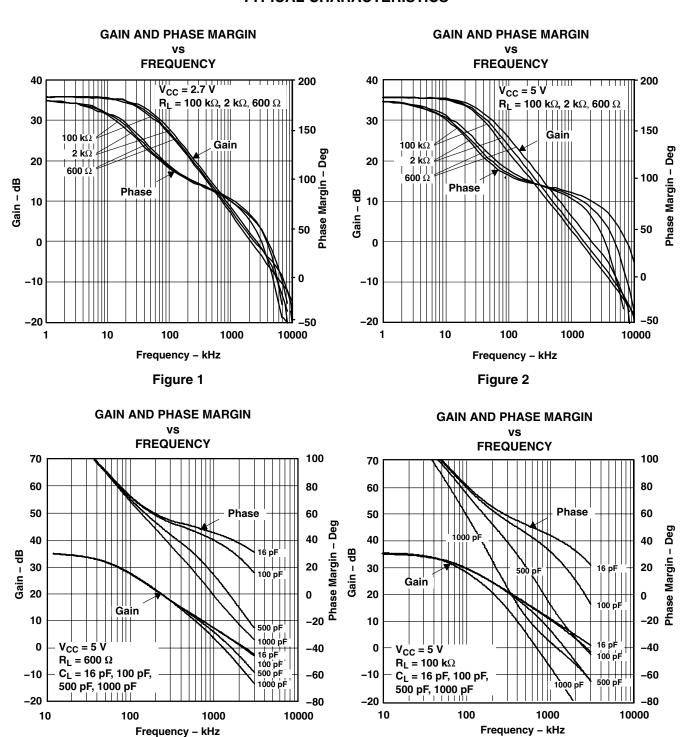
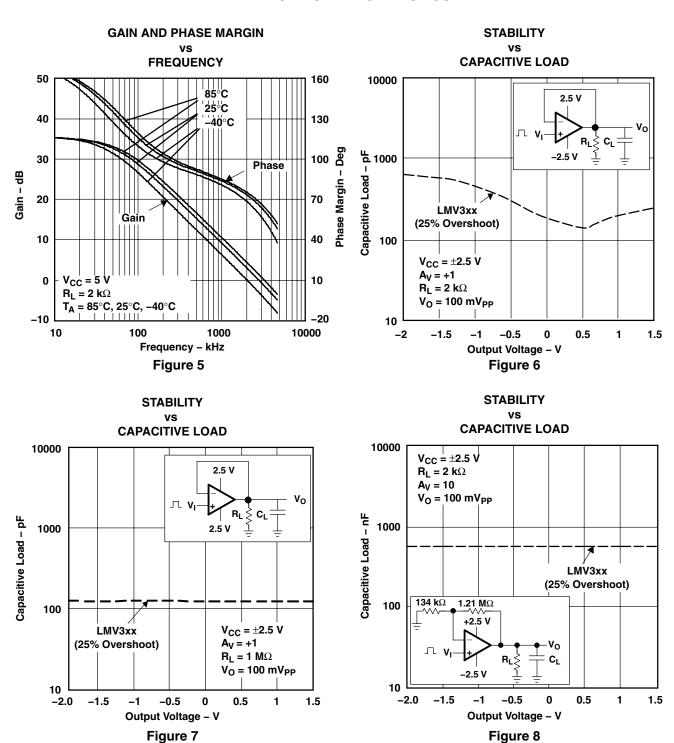
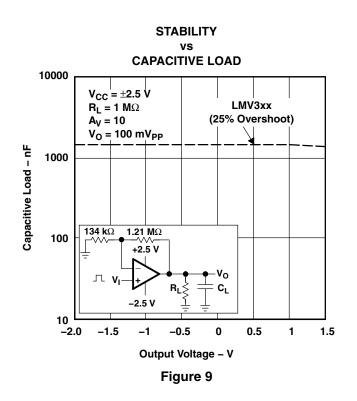




Figure 4

Figure 3





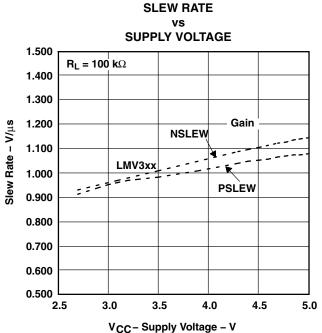
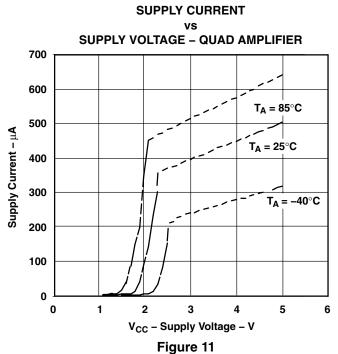
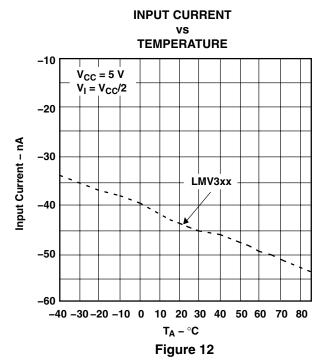


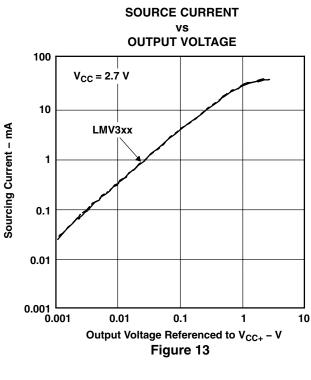
Figure 10

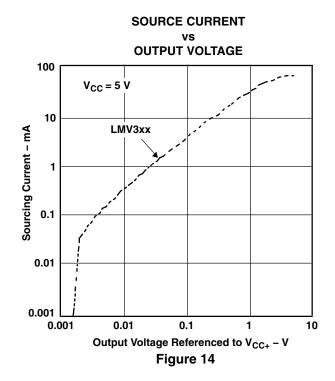


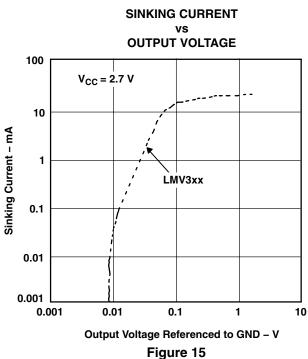


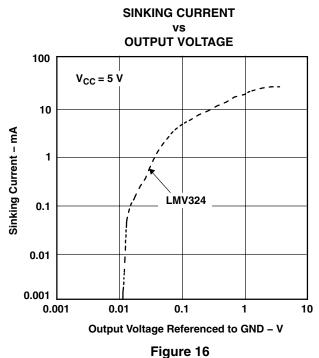
TEXAS INSTRUMENTS

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POST OFFICE BOX 1443 • HOUSTON, TEXAS 77251-1443

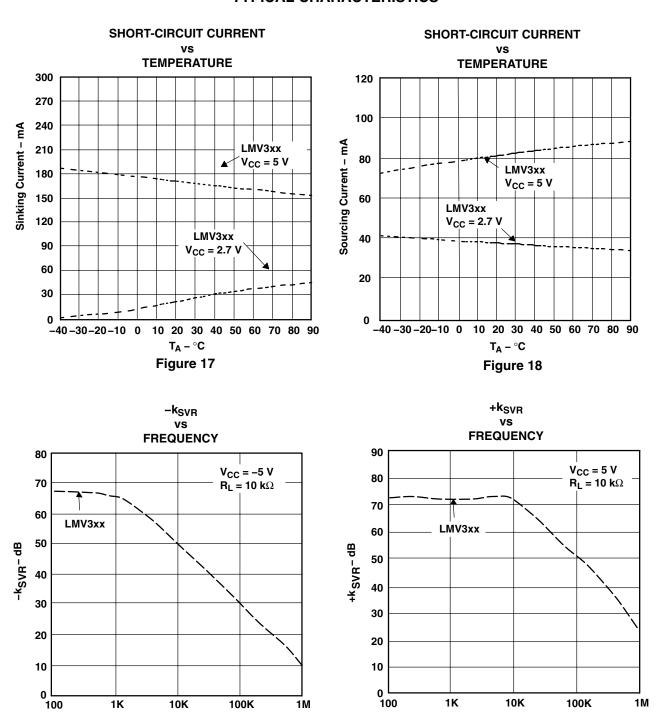








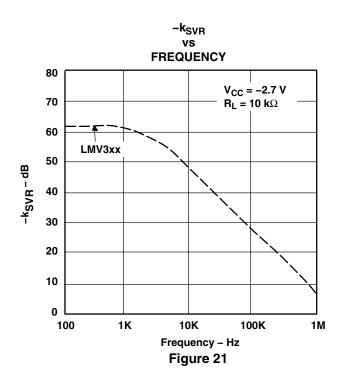
TYPICAL CHARACTERISTICS

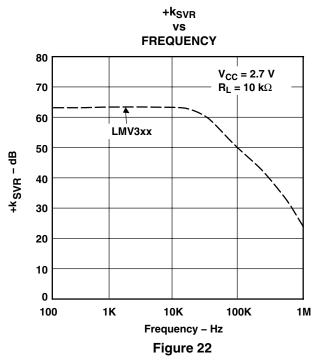


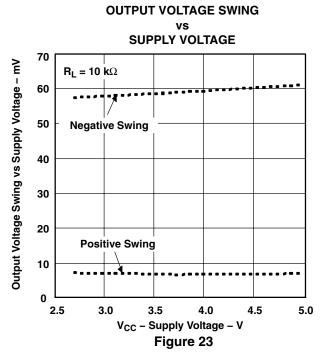


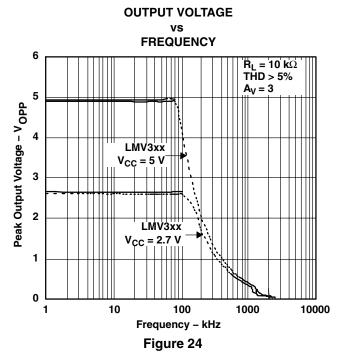
Frequency – Hz Figure 19 Frequency - Hz

Figure 20

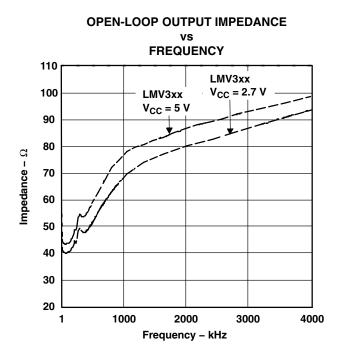








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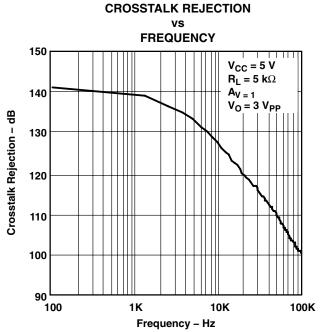


Figure 26

TYPICAL CHARACTERISTICS

NONINVERTING LARGE-SIGNAL PULSE RESPONSE

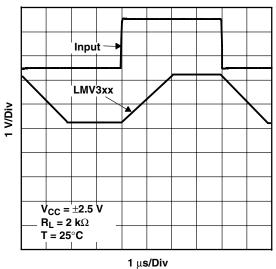


Figure 27

NONINVERTING LARGE-SIGNAL PULSE RESPONSE

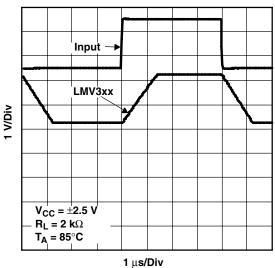


Figure 28

NONINVERTING LARGE-SIGNAL PULSE RESPONSE

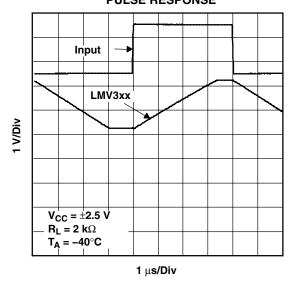
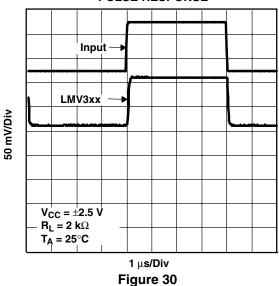


Figure 29

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TYPICAL CHARACTERISTICS

NONINVERTING SMALL-SIGNAL PULSE RESPONSE



NONINVERTING SMALL-SIGNAL PULSE RESPONSE

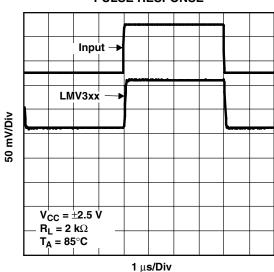


Figure 31

NONINVERTING SMALL-SIGNAL

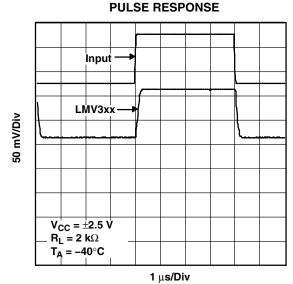


Figure 32

TYPICAL CHARACTERISTICS

INVERTING LARGE-SIGNAL PULSE RESPONSE

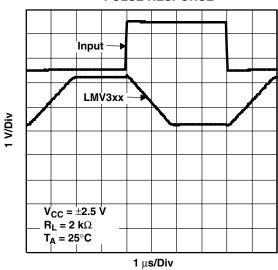


Figure 33

INVERTING LARGE-SIGNAL PULSE RESPONSE

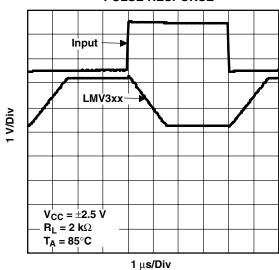


Figure 34

INVERTING LARGE-SIGNAL PULSE RESPONSE

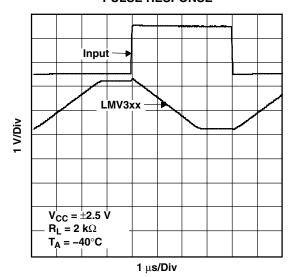
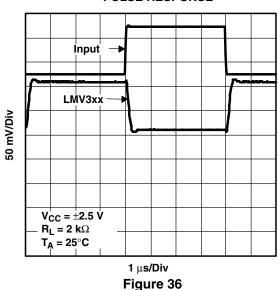


Figure 35

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TYPICAL CHARACTERISTICS

INVERTING SMALL-SIGNAL PULSE RESPONSE



INVERTING SMALL-SIGNAL PULSE RESPONSE

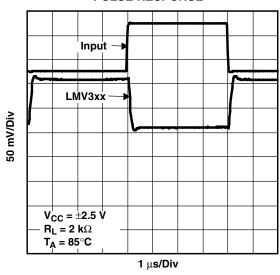


Figure 37

INVERTING SMALL-SIGNAL PULSE RESPONSE

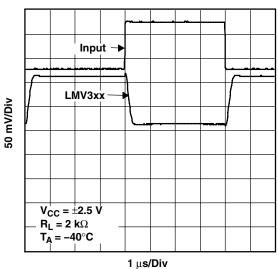
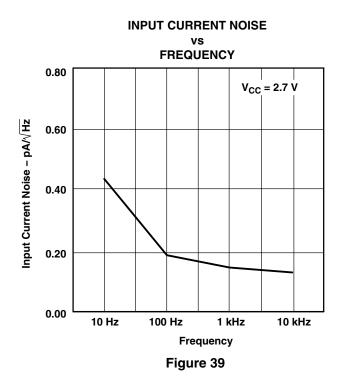
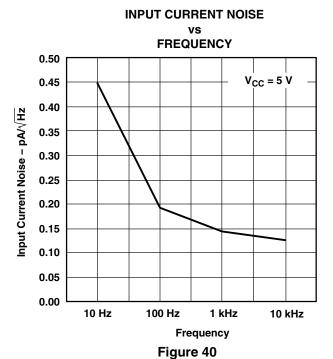
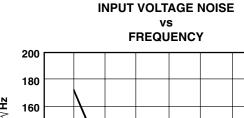
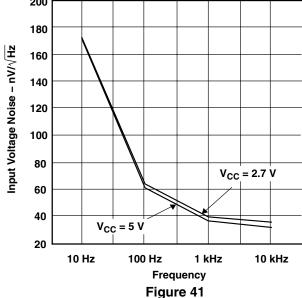


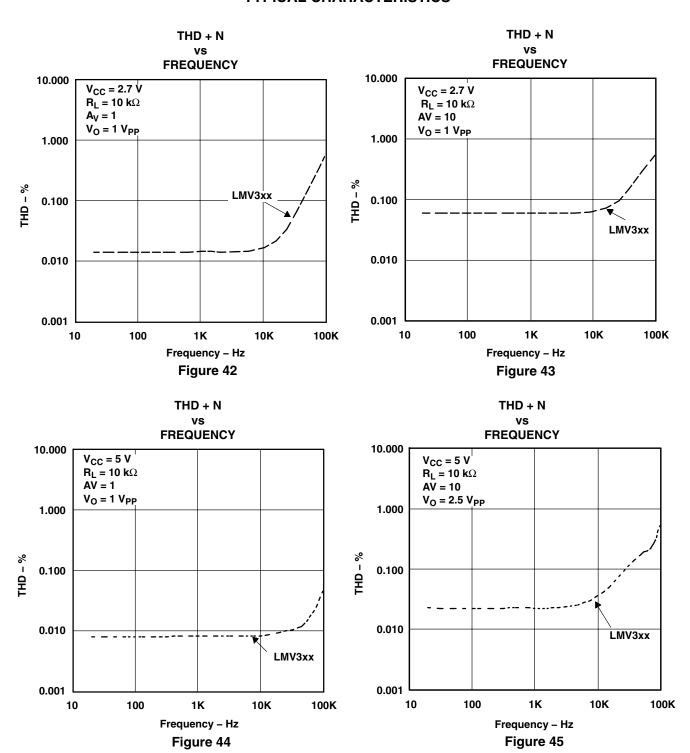
Figure 38











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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing			(2)		(3)		(4)	
LMV324QDQ1	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 125		
LMV358QDQ1	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 125		
LMV358QPWQ1	OBSOLETE	TSSOP	PW	8		TBD	Call TI	Call TI	-40 to 125		

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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OTHER QUALIFIED VERSIONS OF LMV324-Q1, LMV358-Q1:

Catalog: LMV324, LMV358

⁽⁴⁾ Only one of markings shown within the brackets will appear on the physical device.





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NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



PW (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



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